

Type 3504 Series

Key Features

High thermal conductivity Aluminum-Nitride substrate.

High Power / Size ratio – 6W in 2512 size.

Thin film power resistors with TCR ±50ppm/°C and tolerance ±1%.

Applications

Power Supplies

Power

Switching



TE are pleased to introduce the new 3504 series. This is a high stability Thin Film Chip Power resistor range offering very high power / size ratio – 6W in 2512 size. The 3504 series offers TCR at ±50ppm/°C and resistance tolerance at ±1% as standard. Resistance values are within the IEC 63 E96 and E24 value grids. The 3504 resistors have accurate and uniform physical dimensions to facilitate automatic placement methods.

Characteristics – Electrical

Braking Systems	Power Rating @ 70°C	6.0W
	Resistance Range	50Ω ~ 30.1ΚΩ
Automation	Temperature Coefficient of resistance	±50PPM/°C
Controls	Max. Operating Voltage	100V
	Max Overload Voltage	200V
	Operating Temperature Range	-55°C ~ 155°C

Notes:

Power rating dependant upon mounting by user

Operating Voltage= v(P*R) or Max. Operating voltage listed above, whichever is lower

Derating Curve



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Dimensions in millimetres unless otherwise specified **Dimensions Shown for** reference purposes only. Specifications subject to change

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Environmental Characteristics

Item	Requirement	Test Method
Temperature Coefficient of Resistance (TCR)	As per TCRs specified in Electrical Characteristics tables	MIL-STD-202 Method 304 +25/-55/+25/+125/+25°C
Short Time Overload	ΔR±0.5%	Actual power handling capability is limited by the end user mounting process. As with any high power chip resistor the ability to remove the heat is critical to the overall performance of the device.
Insulation Resistance	>9999 MΩ	MIL-STD-202 Method 302 Apply 100VDC for 1 minute
Endurance	ΔR±1%	MIL-STD-202 Method 108 70±2°C, RCWV for 1000 hrs with 1.5 hrs "ON" and 0.5 hrs "OFF"
Damp Heat with Load	ΔR±0.4%	MIL-STD-202 Method 103 40±2°C, 90~95% R.H. RCWV for 1000 hrs with 1.5 hrs "ON" and 0.5 hrs "OFF"
Solderability	95% min. coverage	MIL-STD-202 Method 208 245±5°C for 3 seconds
Resistance to Soldering Heat	ΔR±0.2%	MIL-STD-202 Method 210 260±5°C for 10 seconds
Low Temperature Operation	ΔR±0.2%	JIS-C-5201-1 4.36 1 hour, -65°C, followed by 45 minutes of RCWV
High Temperature Exposure	ΔR±0.2%	MIL-STD-202 Method 108 At +155°C for 1000 hours
Thermal Shock	ΔR±0.2%	MIL-STD-202F Method 107 -55°C ~150°C, 100 cycles

RCWV (Rated continuous working voltage)= √(P*R) or Max. Operating voltage whichever is lower Reference Standards: MIL-STD-202, JIS-C 5201

Storage Temperature: 25±3°C; Humidity < 80%RH Shelf Life: 2 years from date of production

Construction and Dimensions

1	Alumina Nitride Substrate	4	Edge Electrode	Ø	Resistor Layer
2	Bottom Electrode	9	Barrier Layer	8	Overcoat
3	Top Electrode	6	External Electrode	9	Marking

Size	L (mm)	W (mm)	T (mm)	D1 (mm)	D2 (mm)	Weight (g) 1000 Pcs
2512	6.30±0.20	3.10±0.20	0.43±0.15	0.70±0.25	1.60±0.25	42.32

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Recommended PCB Plan



Size	A (mm)	B (mm)	C (mm)
2512	2.77	2.31	3.20±0.2

NB. Use a PCB with a copper thickness of two ounces

Solder Profile (IPC/JEDEC J-STD-020



Marking

4 digit marking – 3 significant figures plus multiplier

Resistance	500Ω	2.2ΚΩ	10ΚΩ	12.5KΩ
Marking	5000	2201	1002	1252

Packaging

Reel Specification

ØA	ØВ	ØC	W	Т	Qty
178.0					
±1.0	±1.0	±0.7	±1.0	±1.0	4000



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Emboss Plastic Tape Specification



Peel force of top cover tape
The peel speed shall be about 300mm/min±5%
The peel force of top cover tape shall be between 20gf to 80gf



How to Order

3504	G	3A	10K	F	TDF
Common Part	TCR	Size	Resistance value	Tolerance	Packaging
3504 – High Power Thin Film Chip Resistor	G – 50ppm	3A - 2512	100R - 100Ω 1K0 - 1000Ω 10K – 10,000Ω	F – 1%	TDF – 1K RL TD – 5K RL

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